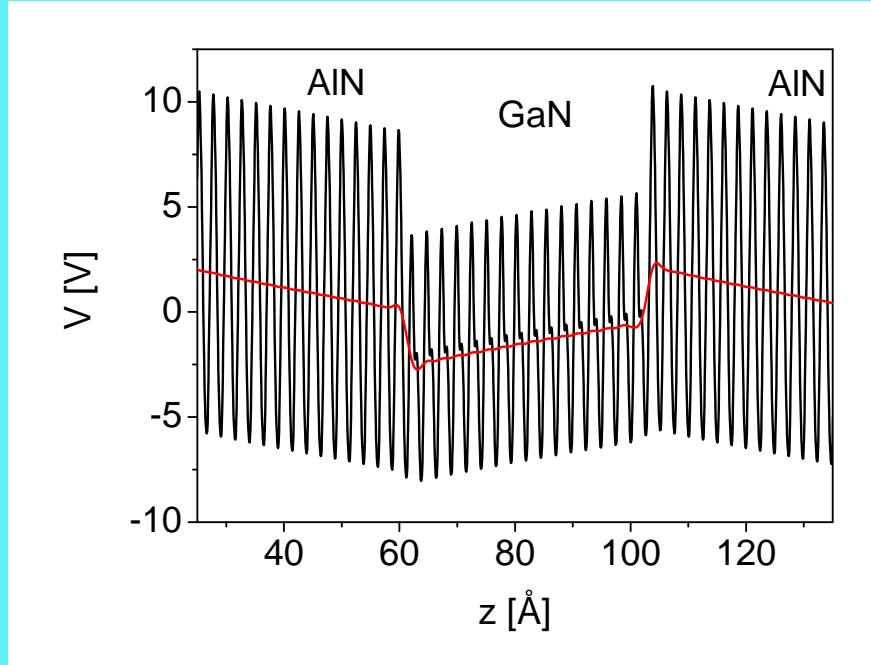


# Polarization, polarization doping and multiquantum wells

P. Strak, P. Kempisty, K. Sakowski, A. Ahmad, Z. Romanowski, S. Krukowski, A. Kamińska, E. Grzanka, M. Leszczyński, M. Sarzyński, G. Muzioł, I. Grzegory

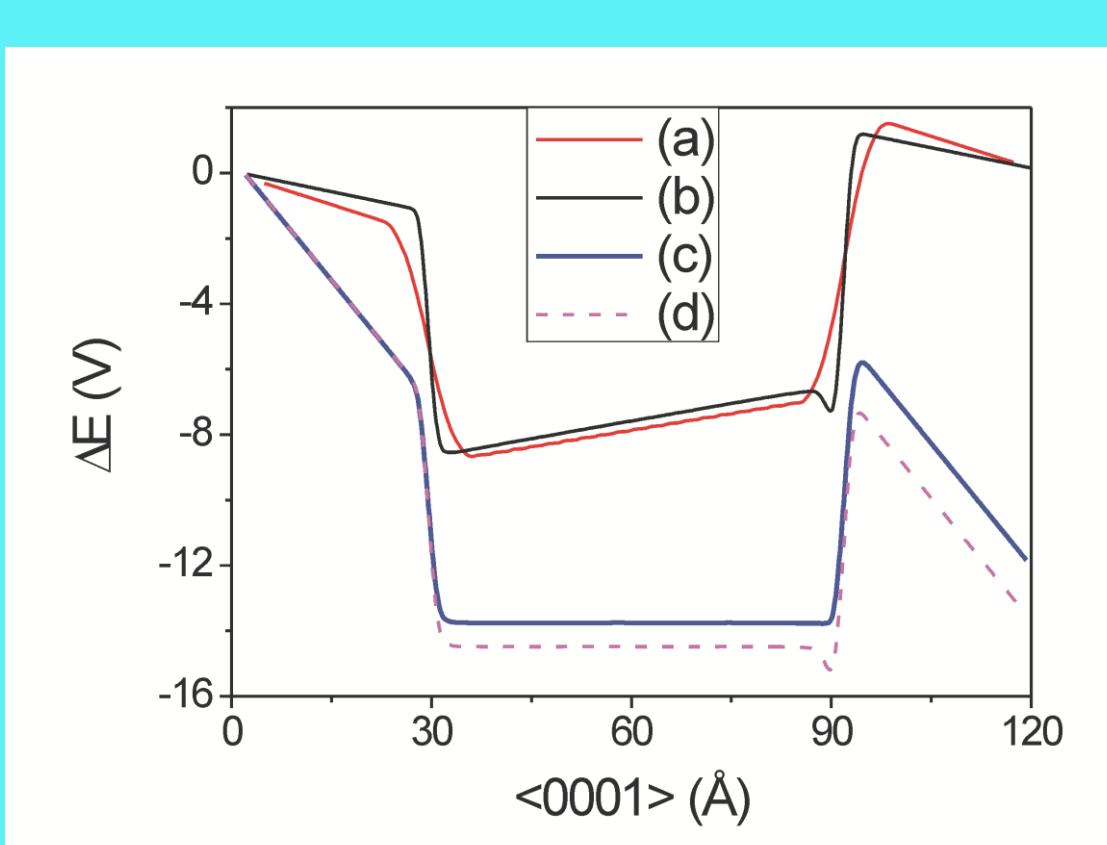
## New methodology – *ab initio* calculations (SIESTA & VASP)

### Potential averaging

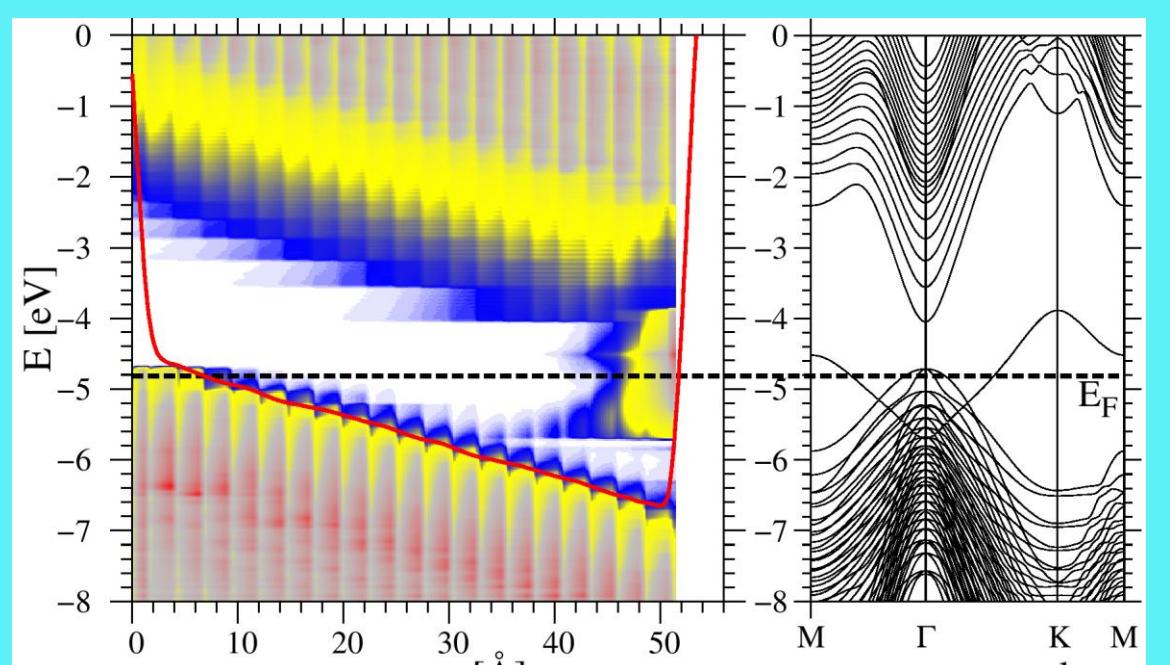


- In-plane and c-axis adjacent averaging
- Smoothed potential profiles
- Charges & dipoles are obtained

### Compensating field in empty space

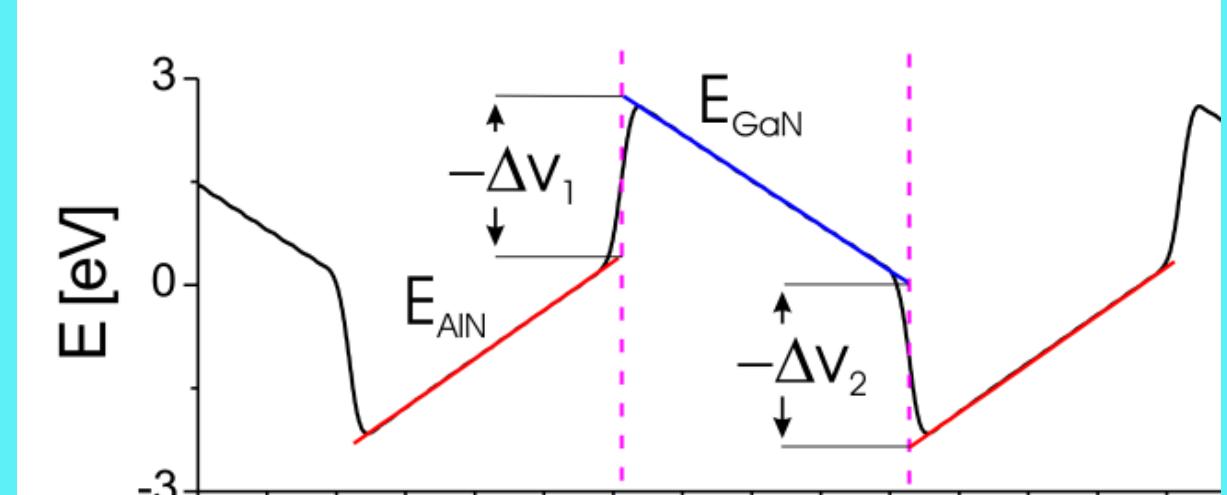


### Real space band visualization



- Fields in the slabs
- Charge in the system

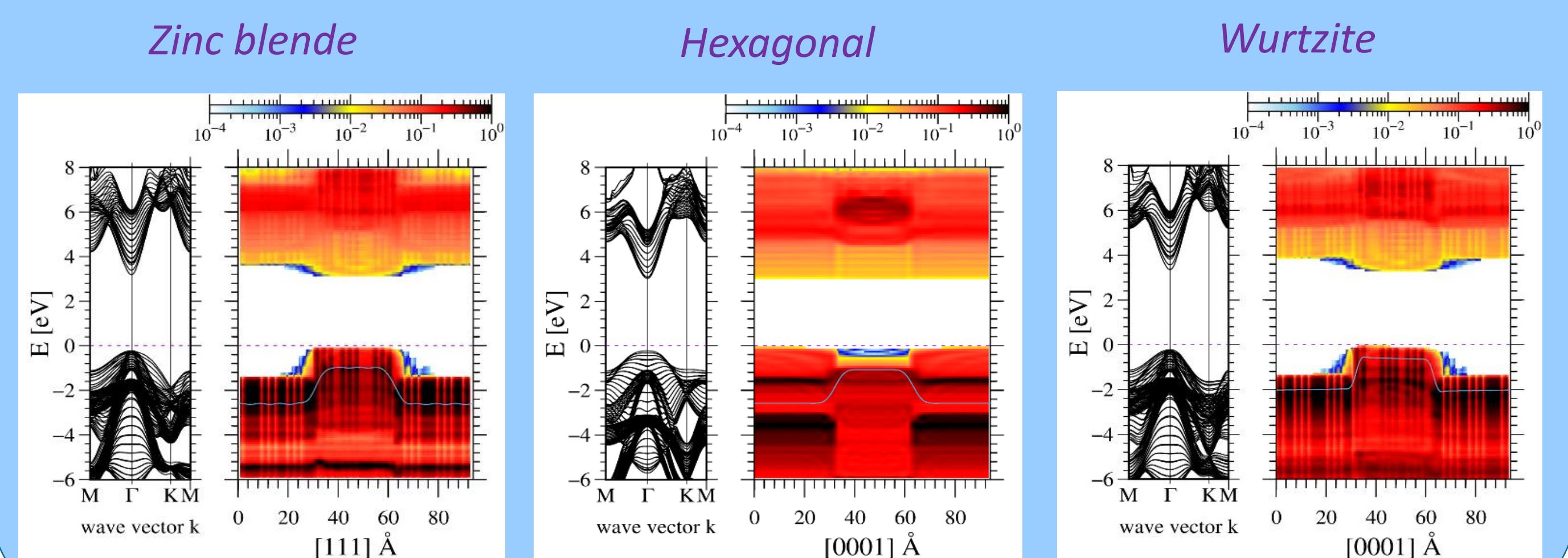
### Charges & dipoles – potential slope and value jumps



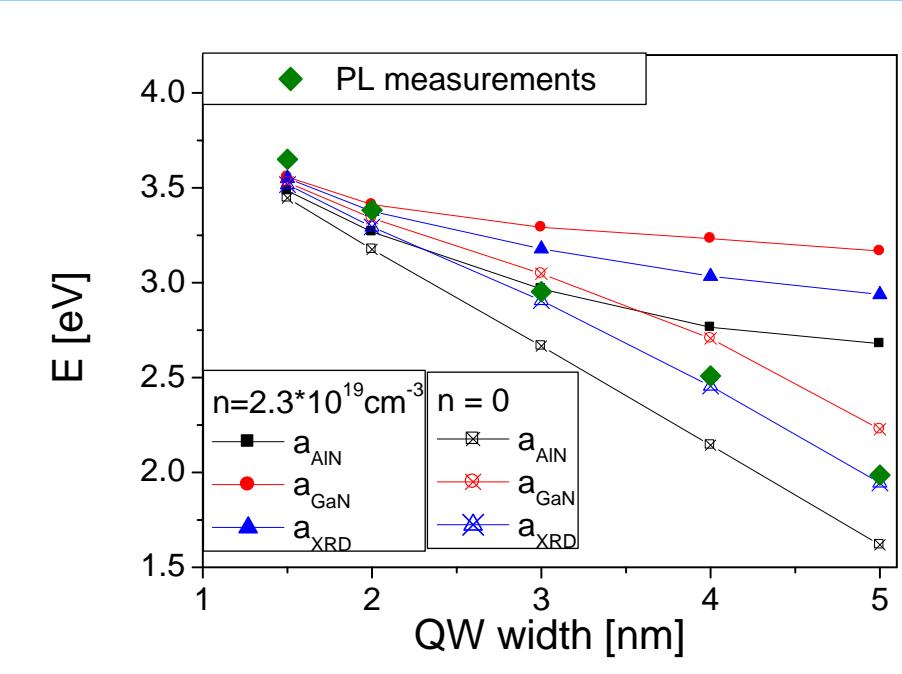
- Interface charge density
- Dipole moment density

## Polarization – Quantum Confined Stark Effect (QCSE)

### Spontaneous polarization & piezo effects 24 AlN-12GaN supercell

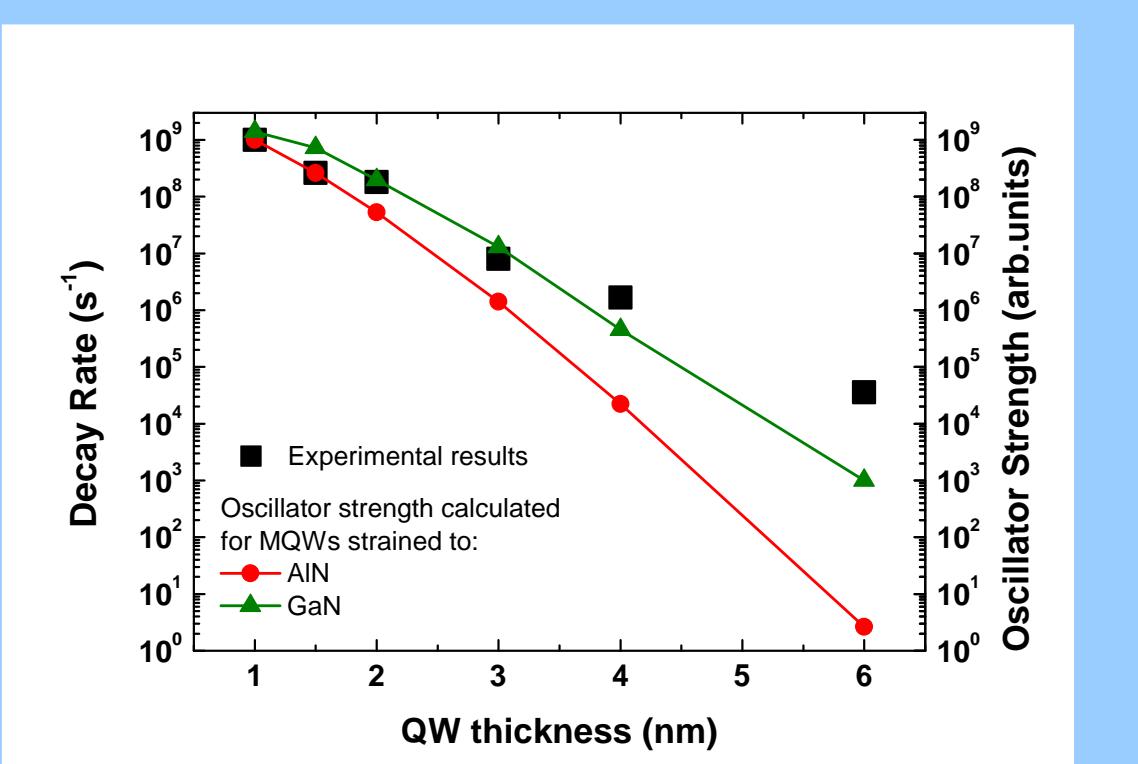


### Recombination energy



- Various widths GaN/AlN MQWs
- Ab initio band-to-band transitions
- Experiment (◆)

### Recombination rates



- Various widths GaN/AlN MQWs
- Ab initio band-to-band transitions
- Experiment (■)

## Multiquantum well devices – LDs & LEDs

### Drift-diffusion equations – discontinuous Galerkin method

$$\begin{aligned} -\nabla \cdot (\varepsilon \nabla \psi) &= \rho - \nabla \cdot \mathbf{J}, \\ -\nabla \cdot (\mu_n p \nabla F_n) &= -qR, \\ -\nabla \cdot (\mu_p p \nabla F_p) &= qR, \\ \rho &= p - n + N_d^+ - N_a^- \\ n(x) &= N_c \cdot \exp\left(\frac{E_n(x) - E_c + q\psi(x)}{kT}\right), \\ p(x) &= N_v \cdot \exp\left(\frac{E_v - E_p(x) - q\psi(x)}{kT}\right), \\ N_d^+(x) &= N_d \left[ 1 + g_d \exp\left(\frac{E_n(x) - E_c + q\psi(x)}{kT}\right) \right] \\ N_a^-(x) &= N_a \left[ 1 + g_a \exp\left(\frac{E_v + E_a - F_p(x) - q\psi(x)}{kT}\right) \right] \\ R_{ABC}(x, N) &= AN + BN^2 + CN^3 \end{aligned}$$

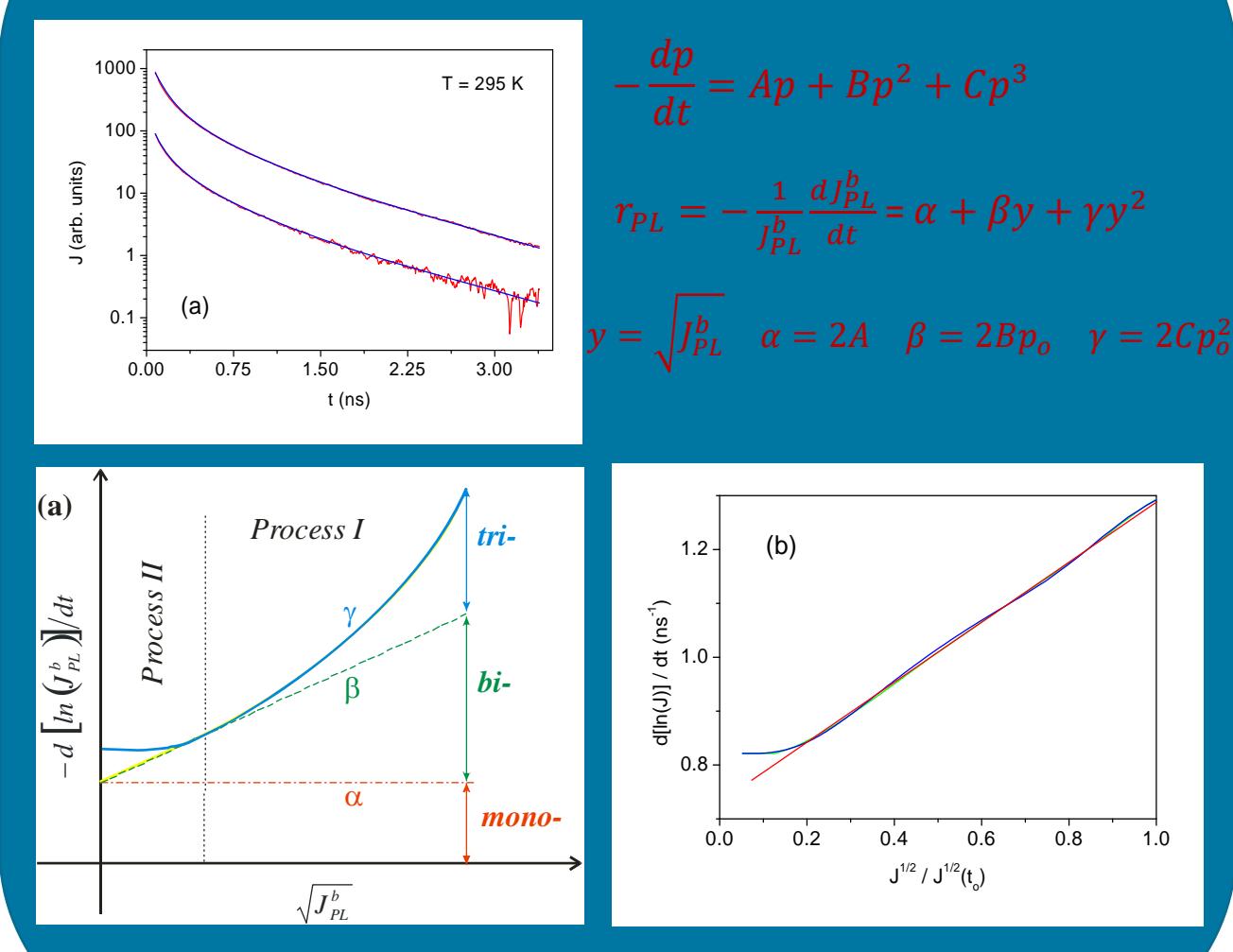
**Poisson & continuity eqs**

**Mobile charge density**

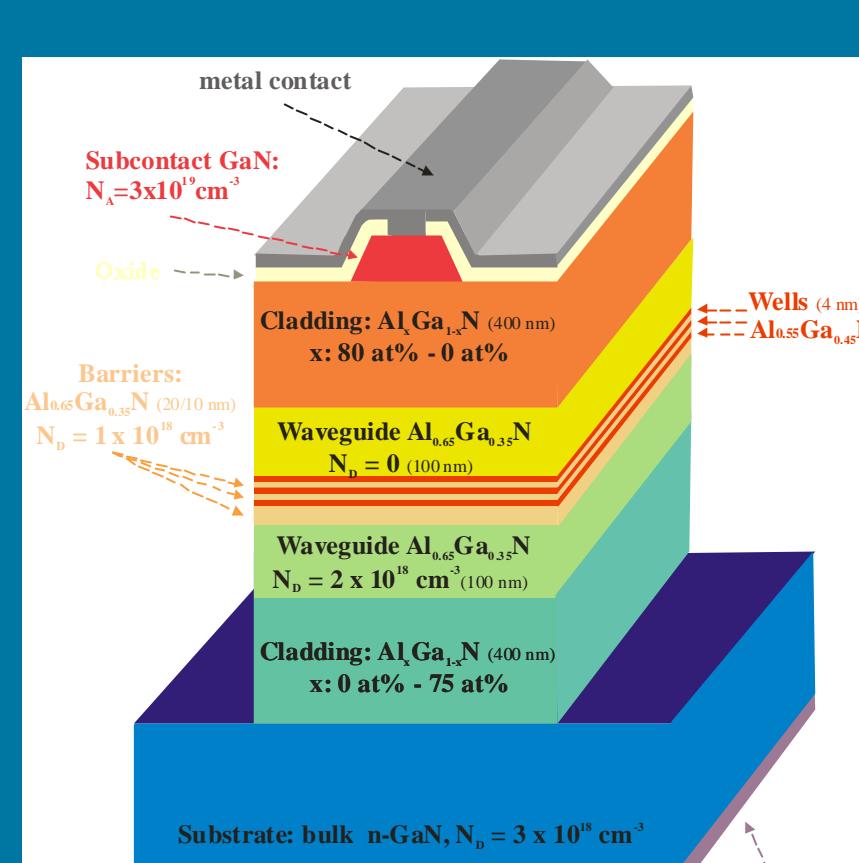
**Defects**

**Recombination**

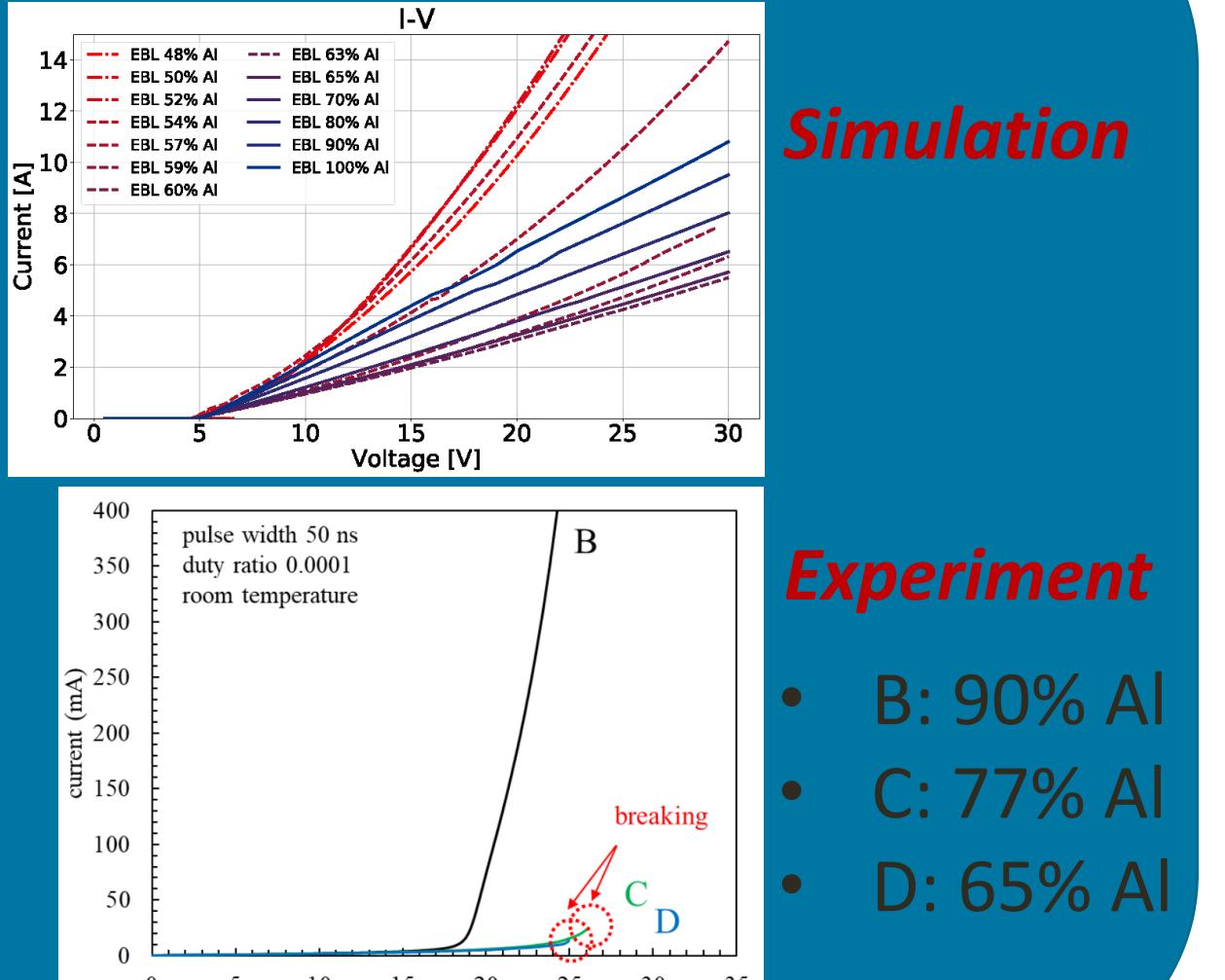
### TRPL - decay constants (ABC)



### LD design

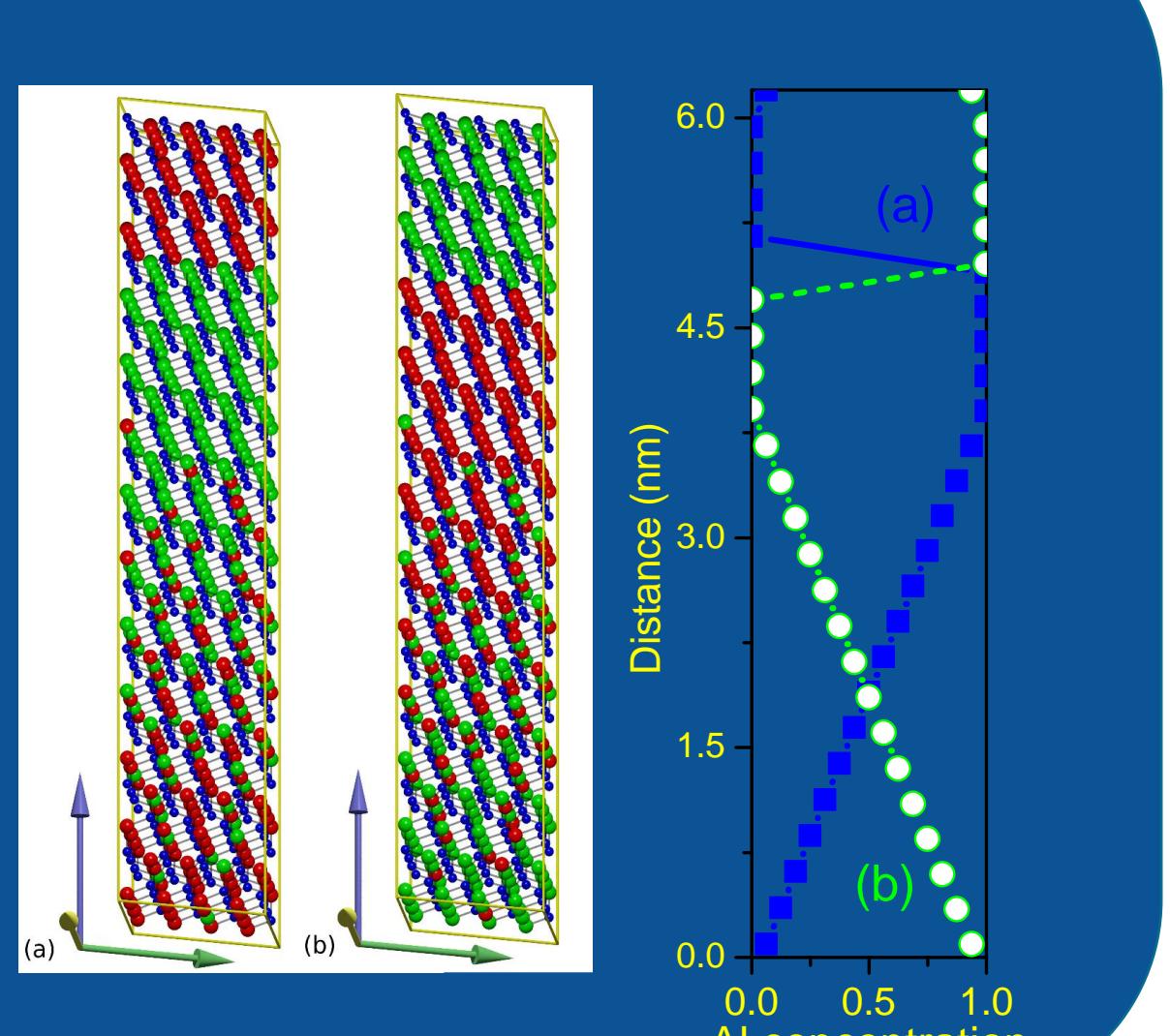


### EBL – Al content

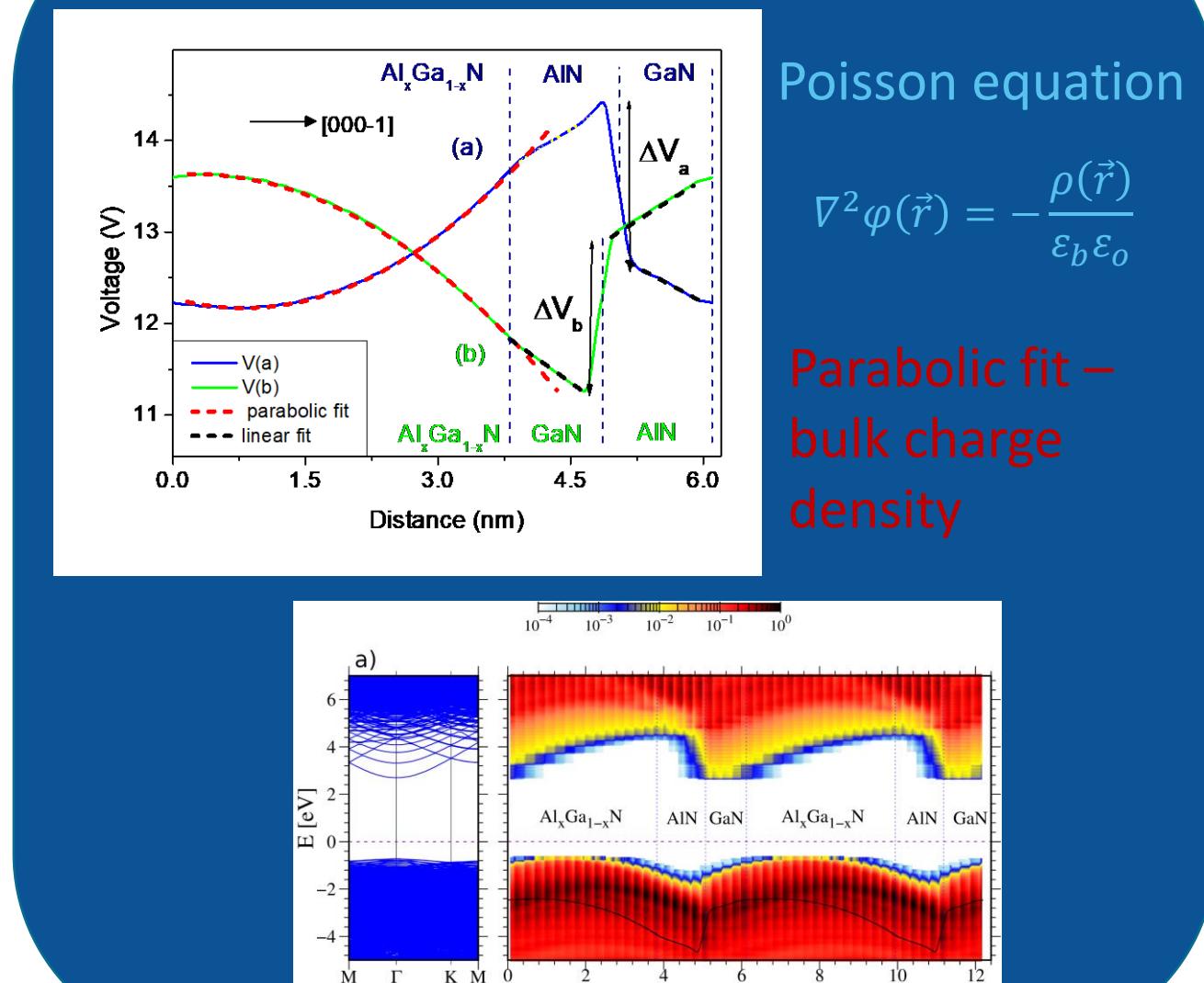


## Polarization doping – route to UV devices

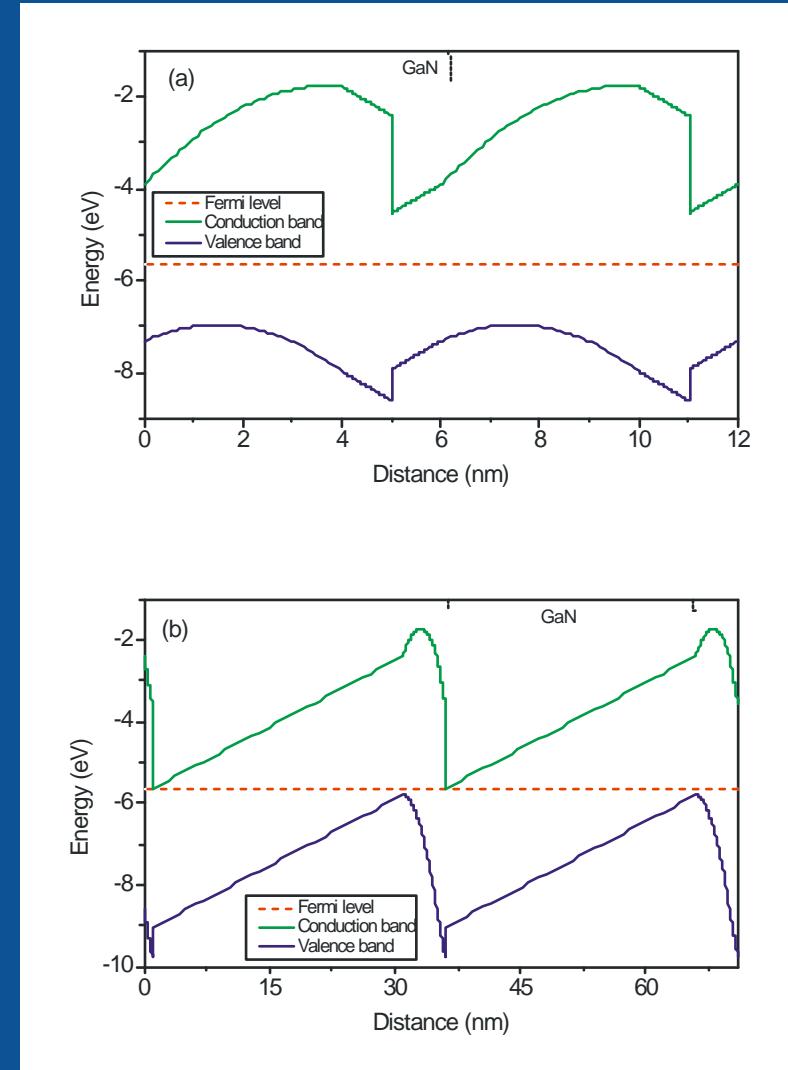
### Atomic model of graded system



### The potential and band profiles



### Emergence of mobile charge



## Summary

- Model of determination of spontaneous polarization
- Averaging procedures for *ab initio*
- Nitride MQWs optical properties
- TRPL based procedure for determination of recombination parameters
- Drift-diffusion equation solution by discontinuous Galerkin method
- Existence of polarization doping charge
- Emergence of mobile charge in polarization doping systems

Use this QR code to see the poster on-line

